



74LV06A

Description

The 74LV06A provides provides six independent inverters with open drain outputs. The device is designed for operation with a power supply range of 2.0V to 5.5V.

The inputs are tolerant to 5.5V allowing this device to be used in a mixed voltage environment. The device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output preventing damaging current backflow when the device is powered down.

The gates perform the Boolean function:

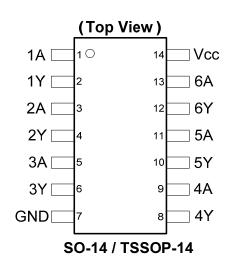
 $\mathbf{Y} = \overline{\mathbf{A}}$

Features

- Wide Supply Voltage Range from 2.0V to 5.5V
- Sinks 12mA at V_{CC} = 4.5V
- CMOS low power consumption
- IOFF Supports Partial -Power Down Operation
- Inputs or Outputs accept up to 5.5V
- Inputs can be driven by 3.3V or 5V allowing for voltage translation applications.
- Schmitt Trigger Action at All Inputs
- ESD Protection Tested per JESD 22
 - Exceeds 200-V Machine Model (A115)
 - Exceeds 2000-V Human Body Model (A114)
- Exceeds 1000-V Charged Device Model (C101)
- Latch-Up Exceeds 100mA per JESD 78, Class I
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

HEX INVERTERS WITH OPEN DRAIN OUTPUTS

Pin Assignments



Applications

- General Purpose Logic
- Power Down Signal Isolation
- Wide array of products such as:
 - PCs, networking, notebooks, ultrabooks, netbooks
 - Computer peripherals, hard drives, CD/DVD ROM
 - TV, DVD, DVR, set top box

- Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 - 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 - 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

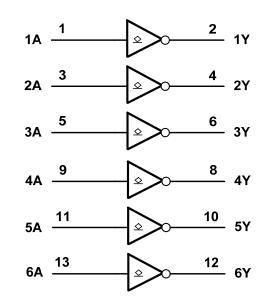
Click here for ordering information, located at the end of datasheet



Pin Descriptions

Pin Number	Pin Name	Description
1	1A	Data Input
2	1Y	Data Output
3	2A	Data Input
4	2Y	Data Output
5	ЗA	Data Input
6	3Y	Data Output
7	GND	Ground
8	4Y	Data Output
9	4A	Data Input
10	5Y	Data Output
11	5A	Data Input
12	6Y	Data Output
13	6A	Data Input
14	Vcc	Supply Voltage

Logic Diagram



Function Table

Input	Output
А	Y
Н	L
L	Z

Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V _{CC}	Supply Voltage Range	-0.5 to +7.0	V
VI	Input Voltage Range note 4	-0.5 to +7.0	V
I _{IK}	Input Clamp Current VI < 0V	-20	mA
I _{OK}	Output Clamp Current V _O < -0V	-50	mA
Ι _Ο	Continuous Output Current $-0.5V < V_0 V_{CC} + 0.5V$	- 25	mA
lcc	Continuous Current Through Vcc	50	mA
I _{GND}	Continuous Current Through GND	-50	mA
TJ	Operating Junction Temperature	-40 to +150	°C
T _{STG}	Storage Temperature	-65 to +150	°C
Ртот	Total Power Dissipation	500	mW

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.



Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Мах	Unit
Vcc	Supply Voltage	—	2.0	5.5	V
VI	Input Voltage	—	0	5.5	V
Vo	Output Voltage	—	0	5.5	V
		2.0V	_	50	μA
I _{OL}	Low-Level Output Current	2.3V to 2.7V	—	2	mA
		3.0V to 3.6V	—	6	mA
		4.5V to 5.5V	—	12	mA
		2.3V to 2.7V	—	200	
Δt/ΔV	Input Transition Rise or Fall Rate	3.0V to 3.6V	—	100	ns/V
	Nate	4.5V to 5.5V	—	20	
T _A	Operating Free-Air Temperature	_	-40	+125	°C

Note: 5. Unused inputs should be held at V_{CC} or Ground.

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Queen had	Demonster	Test Conditions		T _A = -40°C	C to +85°C	T _A = -40°C	to +125°C	Unit
Symbol	Parameter	Test Conditions	Vcc	Min	Max	Min	Max	Unit
		—	2.0V	1.5	—	1.5	—	
.,	High-Level Input	—	2.3V to 2.7V	V _{CC} X 0.7	—	V _{CC} X 0.7	—	V
V _{IH}	Voltage	—	3.0V to 3.6V	V _{CC} X 0.7	—	V _{CC} X 0.7	—	
		—	4.5V to 5.5V	V _{CC} X 0.7	—	V _{CC} X 0.7	—	_
	V _{IL} Low-Level Input Voltage	—	2.0V	—	0.5	—	0.5	V
		—	2.3V to 2.7V	—	V _{CC} X 0.3	—	V _{CC} X 0.3	
VIL		—	3.0V to 3.6V	—	V _{CC} X 0.3	—	V _{CC} X 0.3	
		—	4.5V to 5.5V	—	V _{CC} X 0.3	—	V _{CC} X 0.3	_
		I _{OL} = 50μA	2.0V to 5.5V	—	0.1	—	0.1	
	Low-Level	I _{OL} = 2mA	2.3V	—	0.4	—	0.4	
V _{OL}	Output Voltage	I _{OL} = 6mA	3.0V	—	0.44	—	0.44	V
		I _{OL} = 12mA	4.5V		0.55	—	0.55	
I _{OFF}	Power Down Leakage Current	V_1 or V_0 = 0 to 5.5V	0V	—	5	—	5	μA
lı	Input Current	V _I =GND or 5.5V	0 to 5.5V	—	±1	—	±1	μA
I _{CC}	Supply Current	$V_1 = GND \text{ or } V_{CC}$ $I_0 = 0$	5.5V	—	20	—	20	μA



Switching Characteristics

V _{CC} = 2.5V	± 0.2V									
Symbol Dor	Parameter	Test Conditions	-	T _A = +25°C		-40°C to +85°C		-40°C to +125°C		Unit
Symbol	Farameter	Test Conditions	Min	Тур	Max	Min	Max	Min	Max	Unit
t _{PLZ}	Propagation Delay A _N	Figure 1	-	5.4	10.4	1	13	1	13	ns
t _{PZL}		C _L = 15pF	—	7.2	10.4	1	13	1	13	115
t _{PLZ}	to Y _N	Figure 1	—	9.7	15.2	1	18	1	18	
t _{PZL}		C _L = 50pF	_	9.3	15.2	1	18	1	18	ns

V_{CC} =3.3V ± 03 V

Symbol	Parameter	Test Conditions		T _A = +25°C		-40°C to +85°C		-40°C to +125°C		Unit
Symbol Parameter	Farameter	Test conditions	Min	Тур	Max	Min	Max	Min	Max	Unit
t _{PLZ}		Figure 1	_	2.9	7.1	1	8.5	1	8.5	
t _{PZL}	Propagation Delay A _N	C _L = 15pF	_	4	7.1	1	8.5	1	8.5	ns
t _{PLZ}	to Y _N	Figure 1	_	4.7	10.6	1	12	1	12	
t _{PZL}		C _L = 50pF		5.8	10.6	1	12	1	12	ns

V_{CC} =5.0V ± 0.5V

Symbol	Parameter	rameter Test Conditions		T _A = +25°C		-40°C to +85°C		-40°C to +125°C		Unit
Symbol Parameter		Min	Тур.	Max	Min	Max	Min	Max	Unit	
t _{PLZ}		Figure 1	_	2.2	5.5	1	6.5	1	6.5	ns
t _{PZL}	Propagation Delay A _N	C _L = 15pF		2.9	5.5	1	6.5	1	6.5	115
t _{PLZ}	to Y _N	Figure 1	_	3.4	7.5	1	8.5	1	8.5	20
t _{PZL}		C _L = 50 pF		4.2	7.5	1	8.5	1	8.5	ns

Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

	Parameter	Test Conditions	Vcc	Тур	Unit
6	Power Dissipation	f = 10MHZ	3.3V	2.5	ъĘ
C _{pd}	Capacitance per Gate	C _L = 50pF	5.0V	3.0	рF

Noise Characteristics

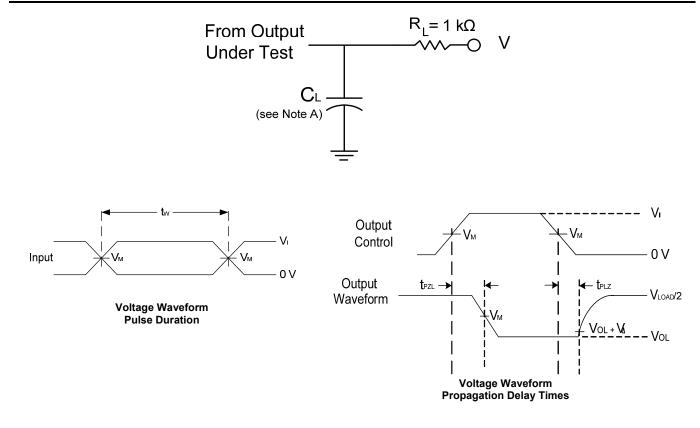
Symbol	Parameter	Min	Тур	Max	Unit
V _{OL(p)}	Quiet output, maximum dynamic V _{OL}	—	0.2	0.8	V
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}	_	-0.1	-0.8	V
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}	_	3.1	_	V
V _{IH(D)}	High Level dynamic input voltage	2.31	—	—	V
VIL(D)	Low Level dynamic input voltage	_		0.99	V

Package Characterisitics

Symbol	Parameter	Test Conditions	Vcc	Min	Тур	Max	Unit
Ci	Input Capacitance	$V_i = V_{CC} - or GND$	2.0 to 5.5V	_	3.3	10	pF







Notes: A. Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate ≤ 10 MHz
- C. The inputs are measured one at a time with one transition per measurement.
- D. For the open drain device t_{PLZ} and t_{PZL} are the same as t_{PD}

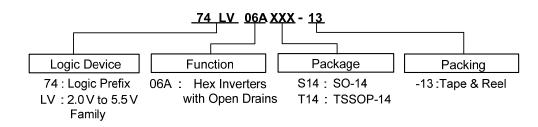
E. t_{PZL} is measured at V_M.

F. t_{PLZ} is measured at V_{OL} +V $_{\Delta}$ where $~V_{\Delta}$ = 0.3V

Figure 1 Load Circuit and Voltage Waveforms



Ordering Information

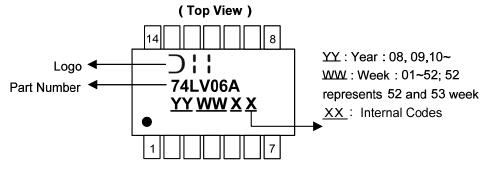


Part Number	Package Code Packaging		13" Tape and Reel			
Part Number	Package Code	(Note 6)	Quantity	Part Number Suffix		
74LV06AS14-13	S14	SO-14	2500/Tape & Reel	-13		
74LV06AT14-13	T14	TSSOP-14	2500/Tape & Reel	-13		

Notes: 6. The taping orientation and tape details can be found at http://www.diodes.com/datasheets/ap02007.pdf

Marking Information

(1) SO14, TSSOP14



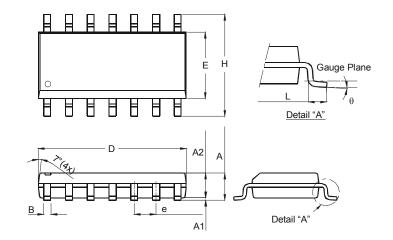
Part Number	Package
74LV06AS14	SO-14
74LV06AT14	TSSOP-14



Package Outline Dimensions (All dimensions in mm.)

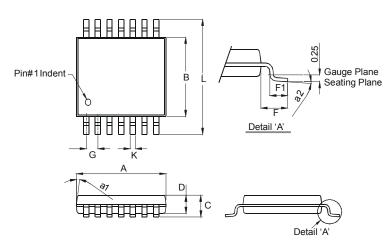
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

Package Type: SO-14



SO-14		
Dim	Min	Max
Α	1.47	1.73
A1	0.10	0.25
A2	1.45 Typ	
В	0.33	0.51
D	8.53	8.74
E	3.80	3.99
е	1.27 Typ	
Н	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Dimensions in mm		

Package Type: TSSOP-14



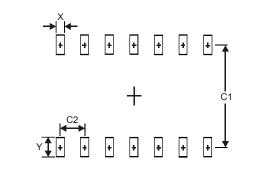
TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
Α	4.9	5.10
В	4.30	4.50
С	_	1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
κ	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		



Suggested Pad Layout

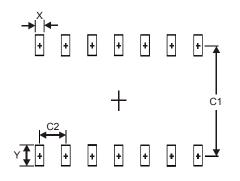
Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.

Package Type: SO-14



Dimensions	Value (in mm)
Х	0.60
Y	1.50
C1	5.4
C2	1.27

Package Type: TSSOP-14



Dimensions	Value (in mm)
Х	0.45
Y	1.45
C1	5.9
C2	0.65



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